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Inclosure Material:

Metal

**Overall Length:** 

0.450 inches

# **Overall Diameter:**

0.875 inches

# Mounting Facility Quantity:

2

### Internal Configuration:

Junction contact

#### **Mounting Method:**

Unthreaded hole

#### Semiconductor Material:

Silicon

## Voltage Rating In Volts Per Characteristic:

100.0 collector to base voltage/static/emitter open and 80.0 collector to emitter voltage/static/base open and 7.0 emitter to base voltage,

static, collector open

## **Current Rating Per Characteristic:**

Between 7.00 amperes source cutoff current and 15.00 amperes source cutoff current

#### **Power Rating Per Characteristic:**

115.0 watts small-signal input power, common-collector absolute

## Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius junction

#### **Special Features:**

Junction pattern arrangement: npn

## Terminal Type And Quantity:

3 uninsulated wire lead

### Shelf Life:

N/a

#### Unit Of Measure:

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#### Demilitarization:

No

# Fiig:

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